

TO-3P

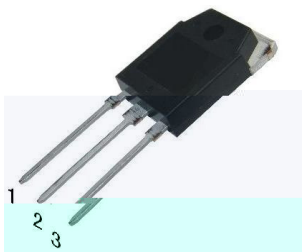
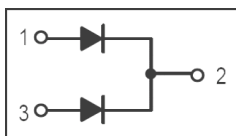
Schottky Barrier Diode in a TO-3P Plastic Package.

Low forward voltage drop, low power losses, High efficiency operation.

OR-ing

DC-DC

For use in high frequency inverters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.



PIN1 Anode PIN 2 Cathode PIN 3 Anode

See Marking Instructions.

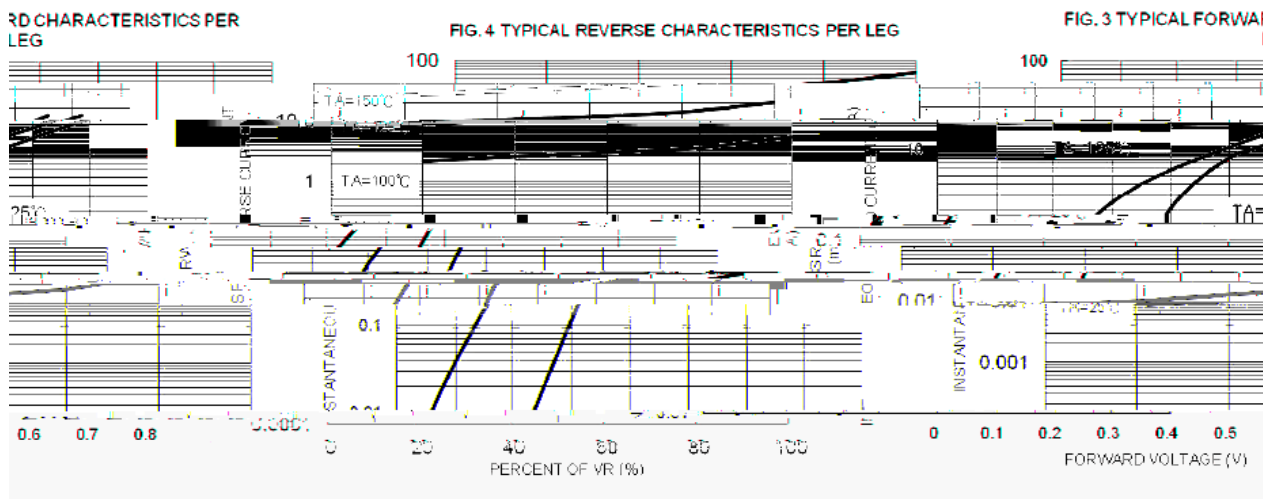
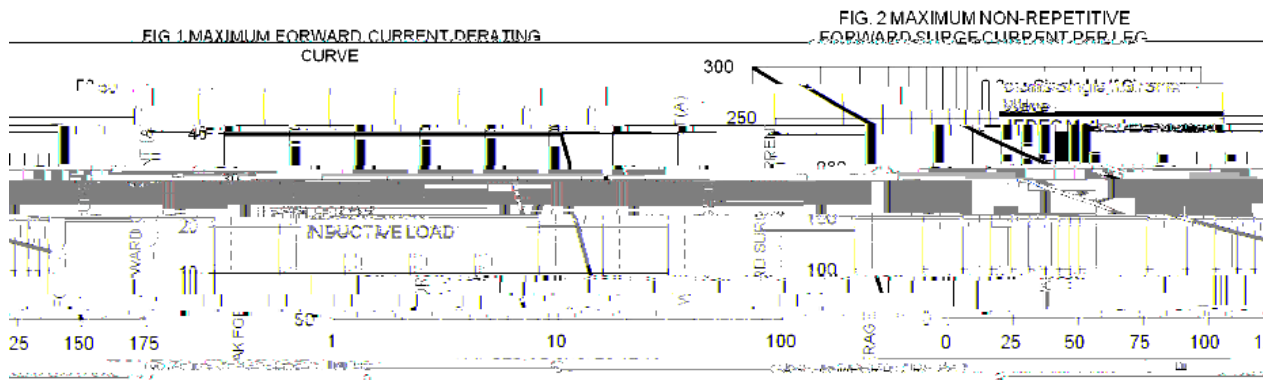
Parameter	Symbol	Rating	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_{DC}	100	V
RMS Reverse Voltage	V_{RMS}	70	V
Average forward current	$I_{F(AV)}$	2 20	A
Non-Repetitive Peak Forward Surge Current	I_{FSM}	300	A
Thermal Resistance Junction to Ambient case	$R_{\theta Jc}$	2.8	/W
Operating and Storage Temperature Range	T_j T_{stg}	-40 +150	

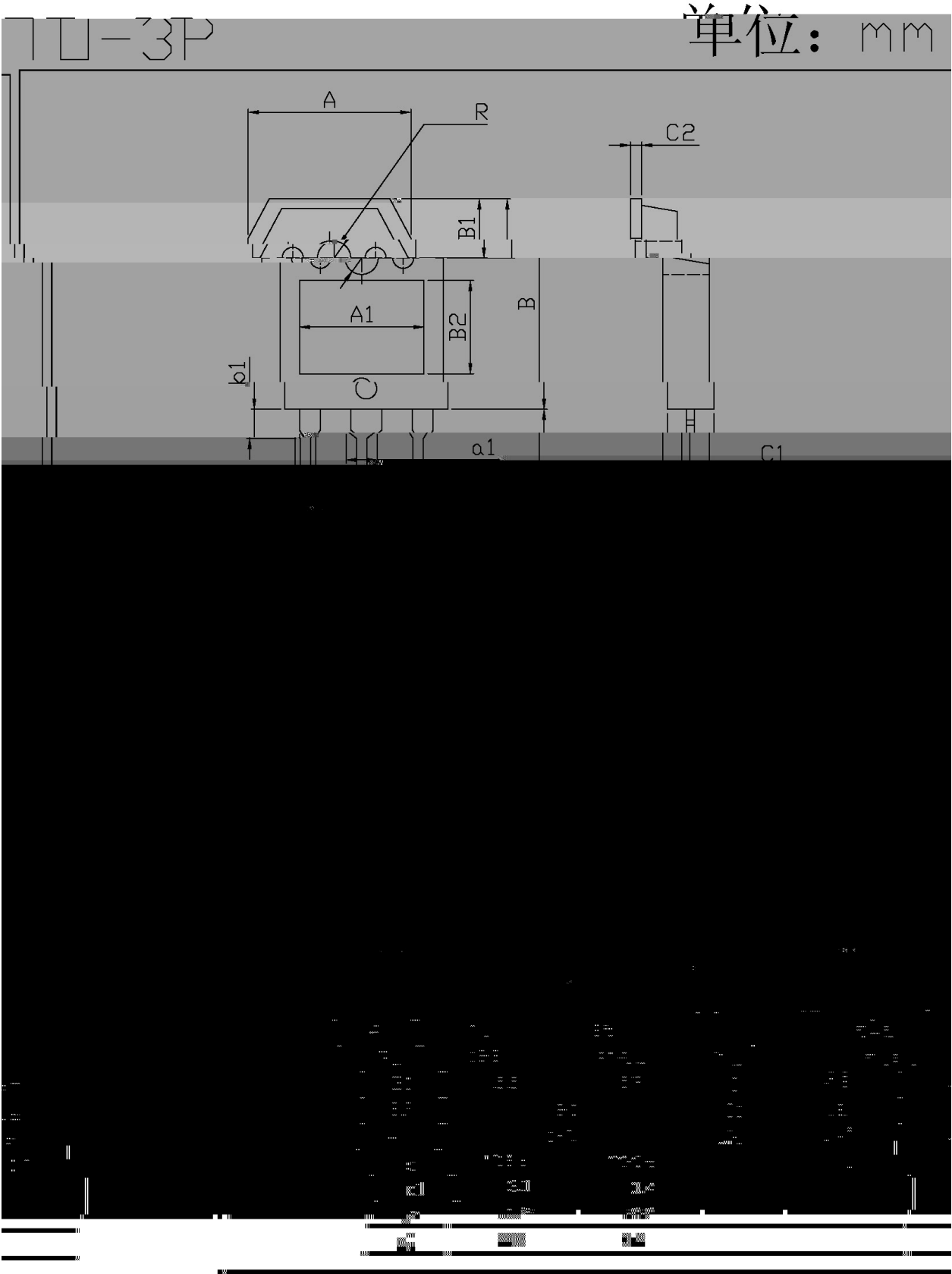
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Reverse Breakdown Voltage	V_{BR}	$I_R=1mA(T_a=25^\circ C)$	100			V

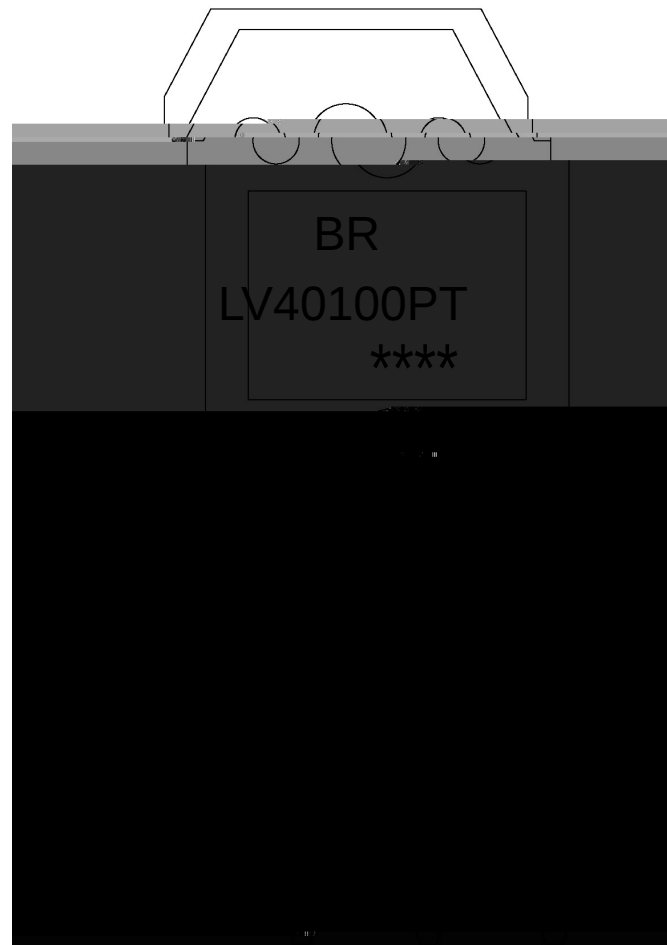
$I_F=57.1Tf3.3$ $C_T=1.572 \times 10^{-10}D0.1030692$ $Tc=1.8w010$

Forward Voltage

 V_F







BR

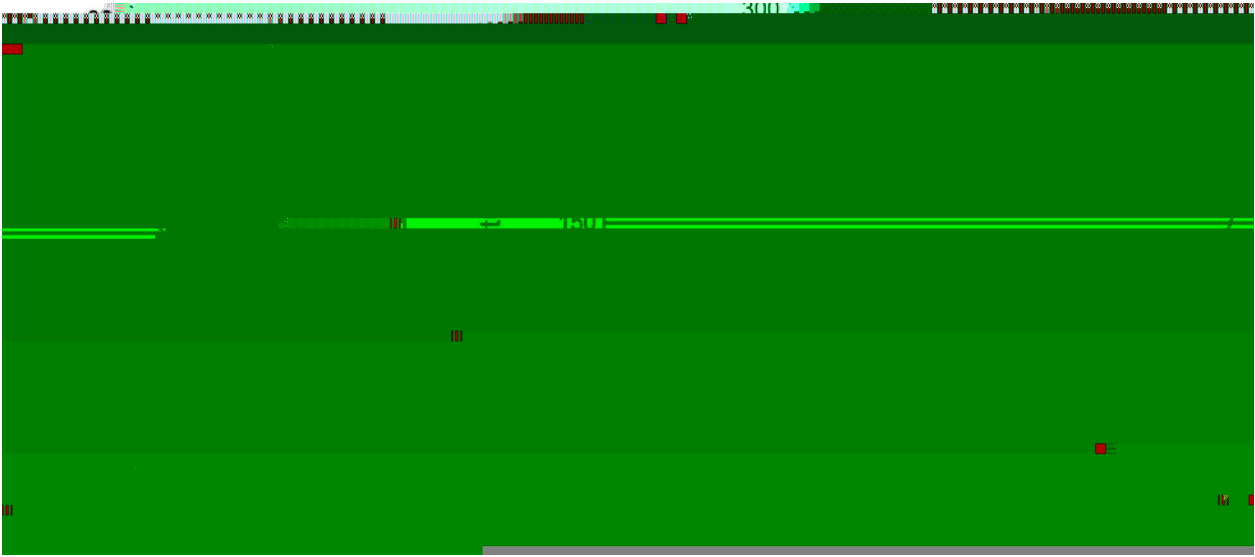
LV40100PT

Note:

BR: Company Code.

LV40100PT: Product Type.

****: Lot No. Code, code change with Lot No.



- 1

25 150

60 90sec;

2

255±5

5±0.5sec;

3

2 10

/sec.
- Note:

1.Preheating:25~150 , Time:60~90sec.

2.Peak Temp.:255±5 , Duration:5±0.5sec.

3. Cooling Speed: 2~10 /sec.

±